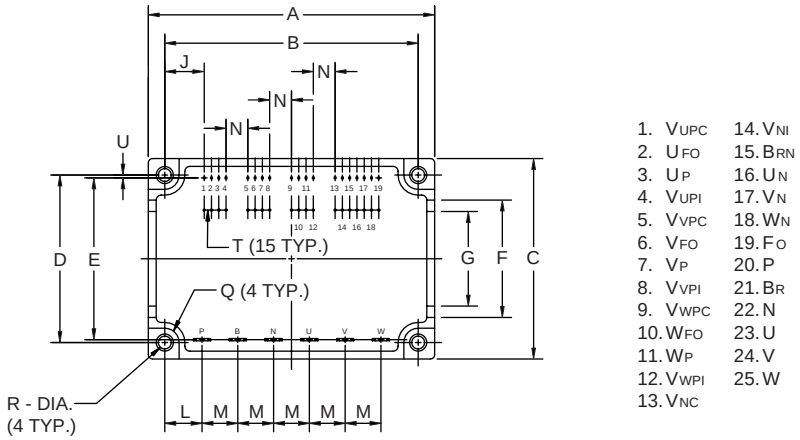
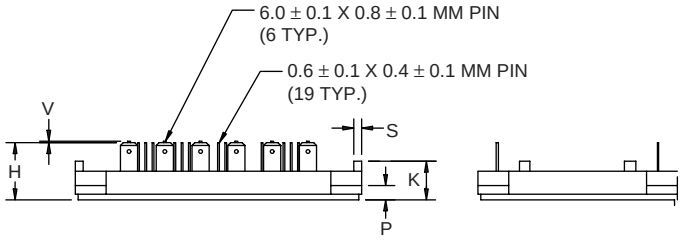
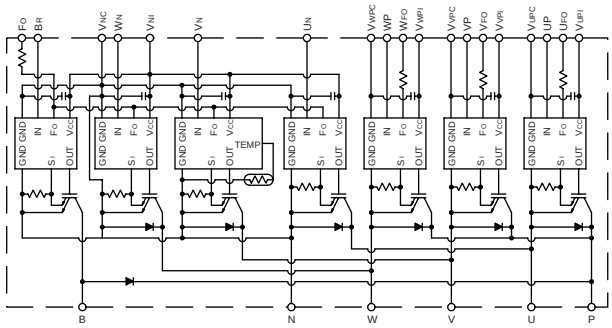
PM50RSK060

FLAT-BASE TYPE
INSULATED PACKAGE



1. V_{UPC}
2. U_{FO}
3. U_P
4. V_{UPI}
5. V_{VPC}
6. V_{FO}
7. V_P
8. V_{VPI}
9. V_{WPC}
10. W_{FO}
11. W_P
12. V_{WPI}
13. V_{NC}
14. V_{NI}
15. B_{RN}
16. U_N
17. V_N
18. W_N
19. F_O
20. P
21. B_R
22. N
23. U
24. V
25. W





Outline Drawing and Circuit Diagram

Dimensions	Inches	Millimeters
A	3.96±0.04	100.5±1.0
B	3.48±0.02	88.5±0.5
C	2.76±0.04	70.0±1.0
D	2.30±0.02	58.5±0.5
E	2.22±0.02	56.5±0.5
F	1.61	41.0
G	1.30	33.0
H	0.75±0.04	19.0±1.0
J	0.542	13.77
K	0.53	13.5

Dimensions	Inches	Millimeters
L	0.51	13.0
M	0.49±0.01	12.5±0.25
N	0.300±0.01	7.62
P	0.22	5.5
Q	0.20 Rad.	Rad. 5.0
R	0.18 Dia.	Dia. 4.5
S	0.108	2.75
T	0.100±0.01	2.54±0.25
U	0.030	0.75
V	0.04	1.0

Description:
Mitsubishi Intelligent Power Modules are isolated base modules designed for power switching applications operating at frequencies to 20kHz. Built-in control circuits provide optimum gate drive and protection for the IGBT and free-wheel diode power devices.

Features:
- ☐ Complete Output Power Circuit
- ☐ Gate Drive Circuit
- ☐ Protection Logic
  - – Short Circuit
  - – Over Current
  - – Over Temperature
  - – Under Voltage

Applications:
- ☐ Inverters
- ☐ UPS
- ☐ Motion/Servo Control
- ☐ Power Supplies

Ordering Information:
Example: Select the complete part number from the table below -i.e. PM50RSK060 is a 600V, 50 Ampere Intelligent Power Module.

Type	Current Rating Amperes	V_{CES} Volts (x 10)
PM	50	60

MITSUBISHI ELECTRIC

PM50RSK060

FLAT-BASE TYPE
INSULATED PACKAGE

Absolute Maximum Ratings, T_j = 25°C unless otherwise specified

	Symbol	Ratings	Units
Power Device Junction Temperature	T_j	-20 to 150	°C
Storage Temperature	T_{stg}	-40 to 125	°C
Case Operating Temperature	T_C	-20 to 100	°C
Mounting Torque, M4 Mounting Screws	—	0.98 ~ 1.47	N · m
Module Weight (Typical)	—	110	Grams
Supply Voltage Protected by OC and SC (V_D = 13.5 - 16.5V, Inverter Part, T_j = 125°C)	$V_{CC(prot.)}$	400	Volts
Isolation Voltage (Main Terminal to Baseplate, AC 1 min.)	V_{iso}	2500	Vrms

Control Sector

Supply Voltage (Applied between V_{UP1}-V_{UPC}, V_{VP1}-V_{VPC}, V_{WP1}-V_{WPC}, V_{N1}-V_{NC})	V_D	20	Volts
Input Voltage (Applied between U_P-V_{UPC}, V_P-V_{VPC}, W_P-V_{WPC}, U_N · V_N · W_N-V_{NC})	V_{CIN}	20	Volts
Fault Output Supply Voltage (Applied between U_{FO}-V_{UPC}, V_{FO}-V_{VPC}, W_{FO}-V_{WPC}, F_O-V_{NC})	V_{FO}	20	Volts
Fault Output Current (Sink Current of U_{FO}, V_{FO}, W_{FO} and F_O Terminal)	I_{FO}	20	mA

IGBT Inverter Sector

Collector-Emitter Voltage (V_D = 15V, V_{CIN} = 15V)	V_{CES}	600	Volts
Collector Current, ±	I_C	50	Amperes
Peak Collector Current, ±	I_{CP}	100	Amperes
Supply Voltage (Applied between P - N)	V_{CC}	450	Volts
Supply Voltage, Surge (Applied between P - N)	$V_{CC(surge)}$	500	Volts
Collector Dissipation	P_C	100	Watts

Brake Sector

Collector-Emitter Voltage (V_D = 15V, V_{CIN} = 15V)	V_{CES}	600	Volts
Collector Current, (T_C = 25°C)	I_C	15	Amperes
Peak Collector Current, (T_C = 25°C)	I_{CP}	30	Amperes
Supply Voltage (Applied between P - N)	V_{CC}	450	Volts
Supply Voltage, Surge (Applied between P - N)	$V_{CC(surge)}$	500	Volts
Collector Dissipation	P_C	43	Watts
Diode Forward Current	I_F	15	Amperes
Diode DC Reverse Voltage	$V_{R(DC)}$	600	Volts

Electrical and Mechanical Characteristics, T_j = 25°C unless otherwise specified

Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Control Sector						
Over Current Trip Level Inverter Part	OC	-20°C ≤ T ≤ 125°C, V_D = 15V	65	88	—	Amperes
Over Current Trip Level Brake Part			18	26	—	Amperes
Short Circuit Trip Level Inverter Part	SC	-20°C ≤ T ≤ 125°C, V_D = 15V	—	132	—	Amperes
Short Circuit Trip Level Brake Part			—	39	—	Amperes
Over Current Delay Time	$t_{off(OC)}$	V_D = 15V	—	10	—	µs
Over Temperature Protection	OT	Trip Level	100	110	120	°C
	OT_r	Reset Level	—	90	—	°C
Supply Circuit Under Voltage Protection	UV	Trip Level	11.5	12.0	12.5	Volts
	UV_r	Reset Level	—	12.5	—	Volts
Supply Voltage	V_D	Applied between V_{UP1}-V_{UPC}, V_{VP1}-V_{VPC}, V_{WP1}-V_{WPC}, V_{N1}-V_{NC}	13.5	15	16.5	Volts
Circuit Current	I_D	V_D = 15V, V_{CIN} = 15V, V_{N1}-V_{NC}	—	44	60	mA
		V_D = 15V, V_{CIN} = 15V, V_{XP1}-V_{XPC}	—	13	18	mA
Input ON Threshold Voltage	$V_{th(on)}$	Applied between	1.2	1.5	1.8	Volts
Input OFF Threshold Voltage	$V_{th(off)}$	U_P-V_{UPC}, V_P-V_{VPC}, W_P-V_{WPC}, U_N · V_N · W_N · B_r-V_{NC}	1.7	2.0	2.3	Volts
PWM Input Frequency	f_{PWM}	3-ϕ Sinusoidal	—	15	20	kHz
Fault Output Current	$I_{FO(H)}$	V_D = 15V, V_{FO} = 15V	—	—	0.01	mA
	$I_{FO(L)}$	V_D = 15V, V_{FO} = 15V	—	10	15	mA
Minimum Fault Output Pulse Width	t_{FO}	V_D = 15V	1.0	1.8	—	ms

Electrical and Mechanical Characteristics, T_j = 25°C unless otherwise specified

Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Units
IGBT Inverter Sector						
Collector Cutoff Current	I_{CES}	$V_{CE} = V_{CES}$, T_j = 25°C	—	—	1.0	mA
		$V_{CE} = V_{CES}$, T_j = 125°C	—	—	10	mA
Diode Forward Voltage	V_{EC}	$-I_C$ = 50A, V_D = 15V, V_{CIN} = 15V	—	2.2	3.3	Volts
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	V_D = 15V, V_{CIN} = 0V, I_C = 50A	—	1.8	2.7	Volts
		V_D = 15V, V_{CIN} = 0V, I_C = 50A, T_j = 125°C	—	1.85	2.78	Volts
Inductive Load Switching Times	t_{on}	V_D = 15V, V_{CIN} = 0 ↔ 15V, V_{CC} = 300V, I_C = 50A, T_j = 125°C	0.4	0.8	2.0	µs
	t_{rr}		—	0.15	0.3	µs
	$t_{C(on)}$		—	0.4	1.0	µs
	t_{off}		—	2.0	2.9	µs
	$t_{C(off)}$		—	0.5	1.0	µs
Brake Sector						
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	V_D = 15V, V_{CIN} = 0V, I_C = 15A, T_j = 25°C	—	2.6	3.5	Volts
		V_D = 15V, V_{CIN} = 0V, I_C = 15A, T_j = 125°C	—	3.0	4.0	Volts
Diode Forward Voltage	V_{FM}	I_F = 15A, V_D = 15V, V_{CIN} = 5V	—	1.7	2.2	Volts
Collector Cutoff Current	I_{CES}	$V_{CE} = V_{CES}$, T_j = 25°C	—	—	1	mA
		$V_{CE} = V_{CES}$, T_j = 125°C	—	—	10	mA

Thermal Characteristics

Characteristic	Symbol	Condition	Min.	Typ.	Max.	Units
Junction to Case Thermal Resistance	$R_{th(j-c)Q}$	Each Inverter IGBT	—	—	1.25	°C/Watt
	$R_{th(j-c)F}$	Each Inverter FWDi	—	—	3.0	°C/Watt
	$Rt_{h(c-f)Q}$	Each Brake IGBT	—	—	2.9	°C/Watt
	$R_{th(c-f)F}$	Each Brake FWDi	—	—	5.4	°C/Watt
Contact Thermal Resistance	$R_{th(c-f)}$	Case to Fin Per Module, Thermal Grease Applied	—	—	0.038	°C/Watt

Recommended Conditions for Use

Characteristic	Symbol	Condition	Value	Units
Supply Voltage	V_{CC}	Applied across P-N Terminals	0 ~ 400	Volts
	V_D	Applied between V_{UP1}-V_{UPC}, V_{N1}-V_{NC}, V_{VP1}-V_{VPC}, V_{WP1}-V_{WPC}	15 ± 1.5	Volts
Input ON Voltage	$V_{CIN(on)}$	Applied between U_P-V_{UPC}, V_P-V_{VPC}, W_P-V_{WPC}, $U_N \cdot V_N \cdot W_N \cdot B_r$-$V_{NC}$	0 ~ 0.8	Volts
Input OFF Voltage	$V_{CIN(off)}$		4.0 ~ V_D	Volts
PWM Input Frequency	f_{PWM}	Using Application Circuit	5 ~ 20	kHz
Minimum Dead Time	t_{dead}	Input Signal	≥ 2.5	μs